GeneSiC™
SEMICONDUCTOR

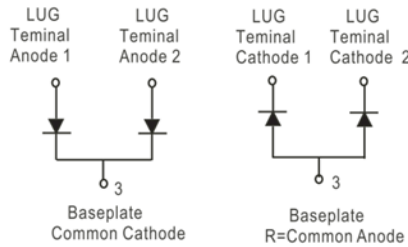## Silicon Power
Schottky Diode

V_{RRM} = 45 V - 100 V

$I_{F(AV)}$ = 500 A

Features

• High Surge Capability
• Types from 45 to 100 V V_{RRM}
• Not ESD Sensitive

Twin Tower Package

LUG Teminal Anode 1   LUG Teminal Anode 2   LUG Teminal Cathode 1   LUG Teminal Cathode 2

Baseplate Common Cathode

Baseplate R=Common Anode

RoHS COMPLIANT

REACH COMPLIANCE

Maximum ratings, at T_j = 25 °C, unless otherwise specified ("R" devices have leads reversed)

Parameter	Symbol	Conditions	MBR50045CT(R)	MBR50060CT(R)	MBR50080CT(R)	MBR500100CT(R)	Unit
Repetitive peak reverse voltage	V_{RRM}		45	60	80	100	V
RMS reverse voltage	V_{RMS}		32	42	57	70	V
DC blocking voltage	V_{DC}		45	60	80	100	V
Operating temperature	T_j		-55 to 150	-55 to 150	-55 to 150	-55 to 150	°C
Storage temperature	T_{stg}		-55 to 150	-55 to 150	-55 to 150	-55 to 150	°C

Electrical characteristics, at Tj = 25 °C, unless otherwise specified

Parameter	Symbol	Conditions	MBR50045CT(R)	MBR50060CT(R)	MBR50080CT(R)	MBR500100CT(R)	Unit
Average forward current (per pkg)	$I_{F(AV)}$	T_C = 125 °C	500	500	500	500	A
Peak forward surge current (per leg)	I_{FSM}	t_p = 8.3 ms, half sine	3500	3500	3500	3500	A
Maximum forward voltage (per leg)	V_F	I_{FM} = 250 A, T_j = 25 °C	0.75	0.78	0.84	0.84	V
Reverse current at rated DC blocking voltage (per leg)	I_R	T_j = 25 °C	1	1	1	1	mA
		T_j = 100 °C	10	10	10	10	
		T_j = 150 °C	50	50	50	50	
Thermal characteristics							
Thermal resistance, junction-case, per leg	$R_{\Theta JC}$		0.30	0.30	0.30	0.30	°C/W

GeneSiC™
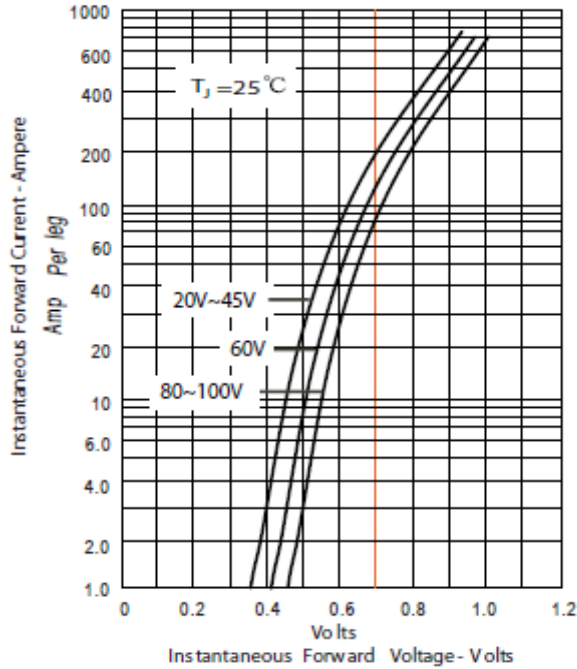SEMICONDUCTOR

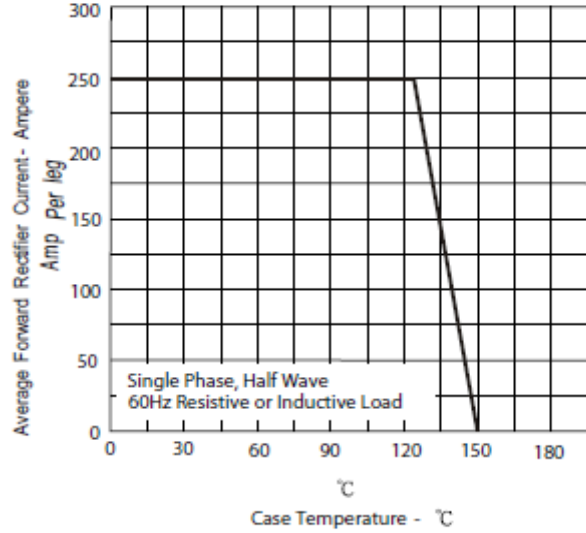Figure .1- Typical Forward Characteristics

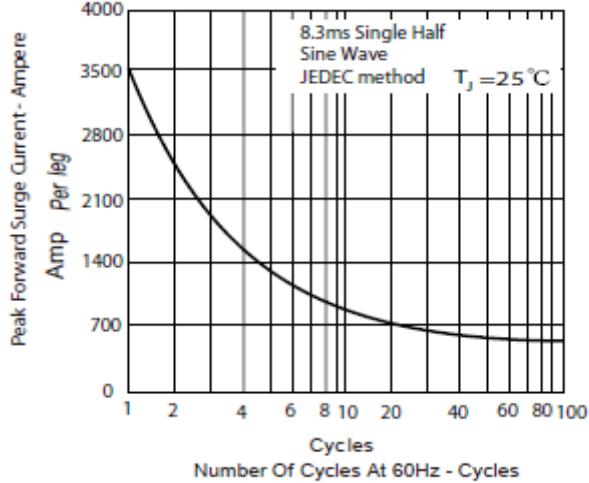Figure .2- Forward Derating Curve
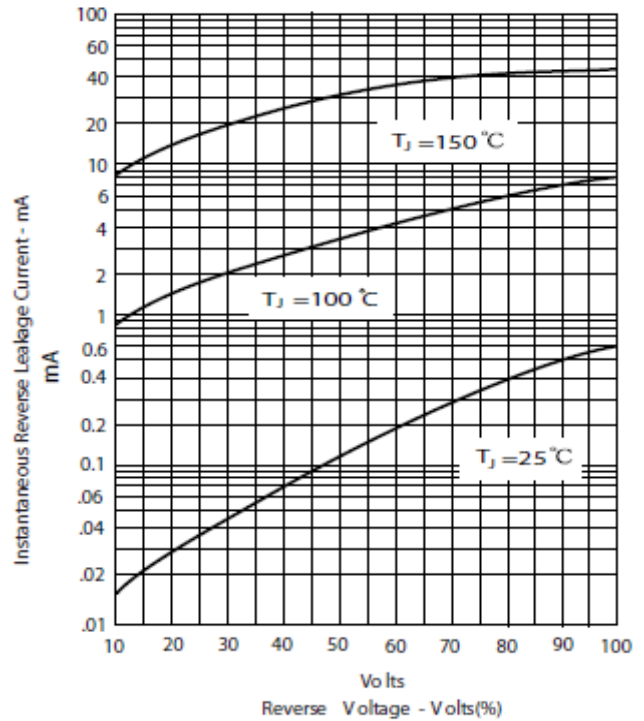

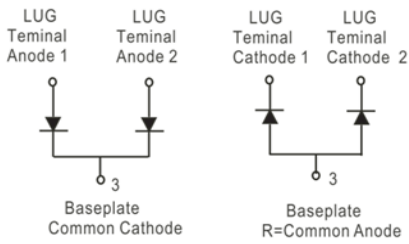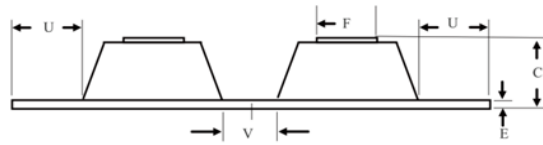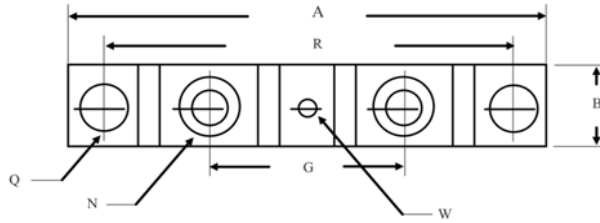Figure .3- Peak Forward Surge Current

Figure .4- Typical Reverse Characteristics

Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.

DIM	Inches		Millimeters	
	Min	Max	Min	Max
A	-----	3.630	-----	92.40
B	0.700	0.800	17.78	20.32
C	-----	0.650	-----	16.51
E	0.130	0.141	3.30	3.60
F	0.482	0.490	12.25	12.45
G	1.368	BSC	34.75	BSC
N	1/4-20 UNC FULL			
Q	0.275	0.290	6.99	7.37
R	3.150	BSC	80.01	BSC
U	0.600	-----	15.24	-----
V	0.312	0.370	7.92	9.40
W	0.180	0.195	4.57	4.95

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